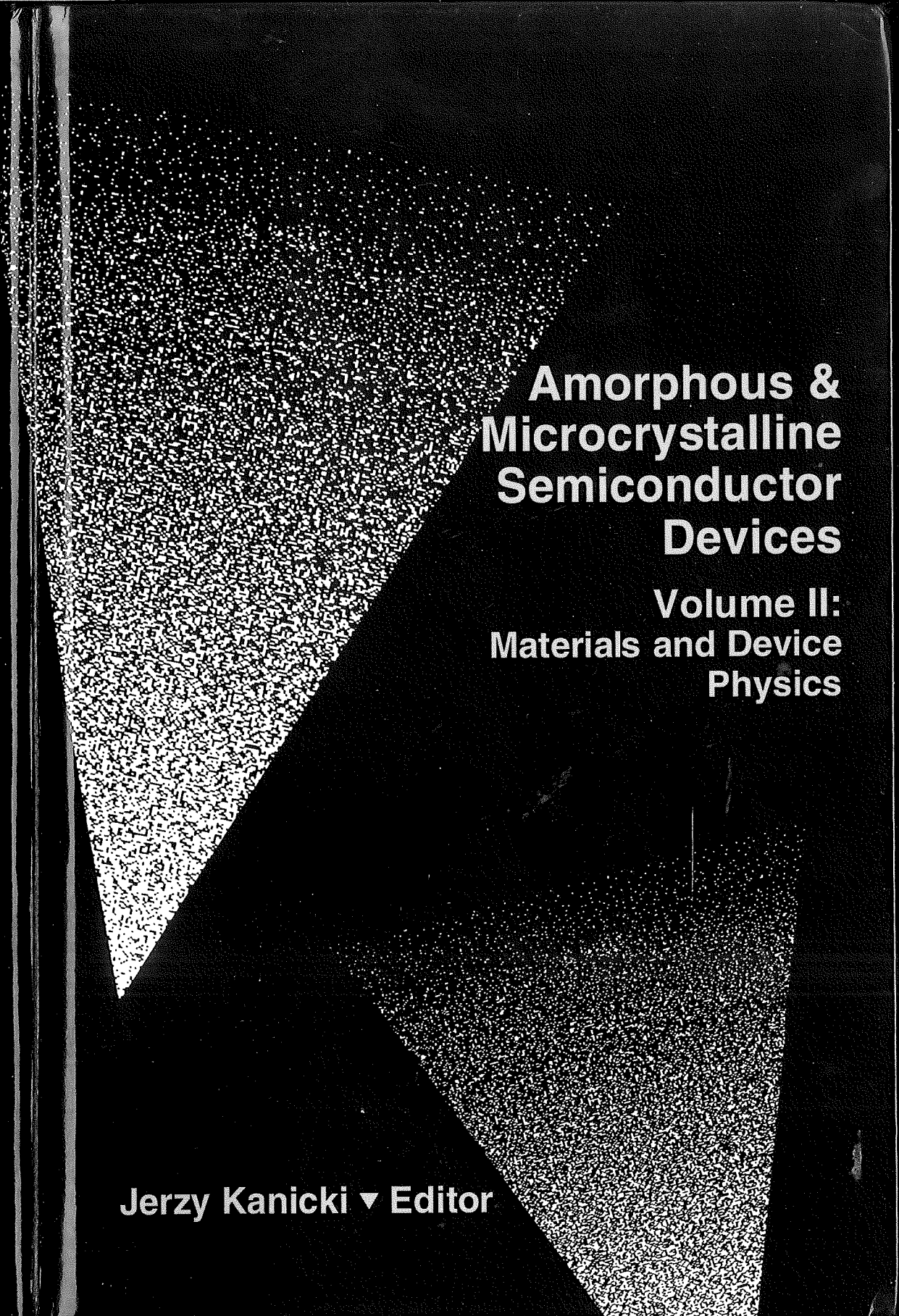


SEL EXHIBIT NO. 2018

INNOLUX CORP. v. PATENT OF SEMICONDUCTOR ENERGY
LABORATORY CO., LTD.

IPR2013-00064

The background of the book cover is a dark, textured surface with a large, irregularly shaped area of fine, white, granular particles. This area is composed of many small, interconnected crystalline structures, creating a complex, porous appearance. The overall effect is that of a microscopic view of a material's internal structure.

**Amorphous &
Microcrystalline
Semiconductor
Devices**

**Volume II:
Materials and Device
Physics**

Jerzy Kanicki ▼ Editor

Library

Volume I: Optoelectronic

Volume II: Materials and

Physics, and Devices,

Ferris-Prabhu

Diagnostics, Edward B.

Assurance,

ed.

**Amorphous and Microcrystalline
Semiconductor Devices
Volume II
Materials and Device Physics**

Jerzy Kanicki, Editor

**Artech House
Boston • London**

Library of Congress Cataloging-in-Publication Data

Amorphous and microcrystalline semiconductor devices : materials and device physics / Jerzy Kanicki.

p. cm.

Includes bibliographical references and index.

ISBN 0-89006-379-6

1. Amorphous semiconductors. 2. Optoelectronics. I. Title.

QC611.8.A5K36 1992
537.6'22—dc20

92-19374
CIP

© 1992 ARTECH HOUSE, INC.
685 Canton Street
Norwood, MA 02062

All rights reserved. Printed and bound in the United States of America. No part of this book may be reproduced or utilized in any form or by any means, electronic or mechanical, including photocopying, recording, or by any information storage and retrieval system, without permission in writing from the publisher.

International Standard Book Number: 0-89006-379-6
Library of Congress Catalog Card Number: 92-19374

10 9 8 7 6 5 4 3 2 1

ion
amulation gate voltage
electostatic potential induced
electostatic potential induced
oltage
ne
ne
ristic time for flat band (or
ld) voltage instability
on energy of τ_c

roscopy
y memory
structure
onductor
effect transistor
deposition
roscopy
y

Chapter 8

Amorphous-Silicon Thin-Film Transistors: Physics and Properties

C. van Berkel
Philips Research Laboratories, Redhill, Surrey, UK

Thin-film transistors (TFT) made with hydrogenated amorphous silicon (a-Si:H) represent an interesting field of study for several reasons. First, there is fundamental interest in amorphous silicon itself. Because in TFTs the Fermi level in the amorphous silicon can be controlled at will, they can be used as powerful tools to investigate various material properties, including density-of-states distribution, photoconductivity, mobility, and stability. Second, interest in a-Si:H TFTs receives commercial impetus because of application in liquid crystal displays, image sensors, and printer arrays. Finally, the device physics of a-Si:H shows many similarities but also striking differences, with established (c-Si) device physics, thus proving useful by throwing established concepts into relief and adding new insight.

In this chapter we will discuss the application of a-Si:H TFTs, review theories and models that have been developed to describe the physics, and, finally, analyze in detail some special issues in the physics of a-Si:H TFTs.

The first section of this chapter gives a brief outline of the main applications of a-Si:H TFTs: liquid crystal displays, printer arrays, and image sensors. We will then discuss the structure and some technological aspects of the transistors. This will be done with reference to standard devices, but a discussion of important topics, such as alternative structures and the choice of gate insulator, is also included. In the third section, the device theory is discussed. Because amorphous silicon is characterized by a continuous distribution of localized states in which the space charge resides and because the distribution of localized states is not necessarily given by a simple expression, solutions of a complete and self-contained theory can only be calculated numerically with the aid of a computer. Here, we will discuss instead a simple model first to establish basic concepts. These will then be used in a qualitative discussion of recent theoretical developments in the literature. Fol-

Explore Litigation Insights

Docket Alarm provides insights to develop a more informed litigation strategy and the peace of mind of knowing you're on top of things.

Real-Time Litigation Alerts



Keep your litigation team up-to-date with **real-time alerts** and advanced team management tools built for the enterprise, all while greatly reducing PACER spend.

Our comprehensive service means we can handle Federal, State, and Administrative courts across the country.

Advanced Docket Research



With over 230 million records, Docket Alarm's cloud-native docket research platform finds what other services can't. Coverage includes Federal, State, plus PTAB, TTAB, ITC and NLRB decisions, all in one place.

Identify arguments that have been successful in the past with full text, pinpoint searching. Link to case law cited within any court document via Fastcase.

Analytics At Your Fingertips



Learn what happened the last time a particular judge, opposing counsel or company faced cases similar to yours.

Advanced out-of-the-box PTAB and TTAB analytics are always at your fingertips.

API

Docket Alarm offers a powerful API (application programming interface) to developers that want to integrate case filings into their apps.

LAW FIRMS

Build custom dashboards for your attorneys and clients with live data direct from the court.

Automate many repetitive legal tasks like conflict checks, document management, and marketing.

FINANCIAL INSTITUTIONS

Litigation and bankruptcy checks for companies and debtors.

E-DISCOVERY AND LEGAL VENDORS

Sync your system to PACER to automate legal marketing.